

# New Jersey Semi-Conductor Products, Inc.

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## VN67 SERIES

N-Channel Enhancement-Mode MOS Transistors

### PRODUCT SUMMARY

PART NUMBER	$V_{(BR)DSS}$ (V)	$r_{DS(ON)}$ ( $\Omega$ )	$I_D$ (A)	PACKAGE
VN67AB	60	3.5	0.79	TO-205AD
VN67AD	60	3.5	1.58	TO-220
VN67AFD	60	3.5	1.37	TO-220SD

Performance Curves: VNDQ06 (See Section 7)

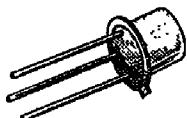
TO-220

1 GATE  
2 & TAB - DRAIN  
3 SOURCE

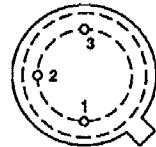
TO-220SD

1 SOURCE  
2 GATE  
3 & TAB - DRAIN

TO-205AD (TO-39)



BOTTOM VIEW

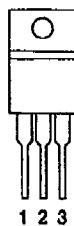


1 SOURCE  
2 GATE  
3 DRAIN & CASE

TO-220/TO-220SD



TOP VIEW



### ABSOLUTE MAXIMUM RATINGS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)<sup>2</sup>

PARAMETERS/TEST CONDITIONS		SYMBOL	VN67AB	VN67AD	VN67AFD	UNITS
Drain-Source Voltage		$V_{DS}$	60	60	60	V
Gate-Source Voltage		$V_{GS}$	$\pm 20$	$\pm 30$	$\pm 30$	
Continuous Drain Current	$T_C = 25^\circ\text{C}$	$I_D$	0.79	1.58	1.37	A
	$T_C = 100^\circ\text{C}$		0.6	1	0.87	
Pulsed Drain Current <sup>1</sup>		$I_{DM}$	3	3	3	
Power Dissipation	$T_C = 25^\circ\text{C}$	$P_D$	5	20	15	W
	$T_C = 100^\circ\text{C}$		2	8	6	
Operating Junction and Storage Temperature		$T_J, T_{stg}$	-55 to 150			$^\circ\text{C}$
Lead Temperature (1/16" from case for 10 seconds)		$T_L$	300			

### THERMAL RESISTANCE

THERMAL RESISTANCE		SYMBOL	VN67AB	VN67AD	VN67AFD	UNITS
Junction-to-Case		$R_{thJC}$	25	6.25	8.3	$^\circ\text{C}/\text{W}$

<sup>1</sup>Pulse width limited by maximum junction temperature

<sup>2</sup>Absolute maximum ratings have been revised from previous data sheet

NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

Quality Semi-Conductors



# VN67 SERIES

ELECTRICAL CHARACTERISTICS <sup>1</sup>			LIMITS			
PARAMETER	SYMBOL	TEST CONDITIONS <sup>4</sup>	TYP <sup>2</sup>	VN67 <sup>4</sup>		UNIT
				MIN	MAX	
<b>STATIC</b>						
Drain-Source Breakdown Voltage	$V_{(BR)DS}$	$V_{GS} = 0 \text{ V}, I_D = 10 \mu\text{A}$	70	60		V
Gate Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 1 \text{ mA}$	1.5	0.8	2.5	
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}$ $V_{GS} = \pm 15 \text{ V}$ $T_C = 125^\circ\text{C}$	$\pm 1$ $\pm 5$		$\pm 100$ $\pm 500$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{GS} = 0 \text{ V}$ $V_{DS} = 60 \text{ V}$ $V_{DS} = 48 \text{ V}, T_C = 125^\circ\text{C}$	0.05 0.3		10 500	$\mu\text{A}$
On-State Drain Current <sup>3</sup>	$I_D$	$V_{DS} = 10 \text{ V}, V_{GS} = 10 \text{ V}$	1.8	1.5		A
Drain-Source On-Resistance <sup>3</sup>	$r_{DS(\text{ON})}$	$V_{GS} = 5 \text{ V}, I_D = 0.3 \text{ A}$	1.8		5	$\Omega$
		$V_{GS} = 10 \text{ V}$ $I_D = 1 \text{ A}$ $T_C = 125^\circ\text{C}$	1.3 2.6		3.5 7	
Forward Transconductance <sup>3</sup>	$g_{FS}$	$V_{DS} = 10 \text{ V}, I_D = 0.5 \text{ A}$	350	170		$\text{mS}$
Common Source Output Conductance <sup>3</sup>	$g_{OS}$	$V_{DS} = 7.5 \text{ V}, I_D = 0.1 \text{ A}$	1100			$\mu\text{s}$
<b>DYNAMIC</b>						
Input Capacitance	$C_{iss}$	$V_{DS} = 25 \text{ V}$ $V_{GS} = 0 \text{ V}$ $f = 1 \text{ MHz}$	35		50	$\text{pF}$
Output Capacitance	$C_{oss}$		25		40	
Reverse Transfer Capacitance	$C_{res}$		5		10	
<b>SWITCHING</b>						
Turn-On Time	$t_{ON}$	$V_{DD} = 25 \text{ V}, R_L = 23 \Omega$ $I_D = 1 \text{ A}, V_{GEN} = 10 \text{ V}, R_G = 25 \Omega$ (Switching time is essentially independent of operating temperature)	8		16	$\text{ns}$
Turn-Off Time	$t_{OFF}$		9.5		15	

- NOTES: 1.  $T_C = 25^\circ\text{C}$  unless otherwise noted.  
 2. For design aid only, not subject to production testing.  
 3. Pulse test; PW = 300  $\mu\text{s}$ , duty cycle  $\leq 2\%$ .  
 4. Data sheet limits and/or test conditions have been revised.